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♥ Title: CN1261458A: Pattern film repair using a gas assisted focused particle beam

system

PDerwent Title: Repair of pattern films on photomasks, X-ray masks, or reticles using gas-

assisted focused particle-beam system where the etchant gas includes

bromine and water vapour [Derwent Record]

@Country: CN China

© Inventor: J. DAVID CASEY JR.; United States of America ANDREW DOYLE; United States of America

Assignee: MICRION CORP. United States of America

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Published / Filed: 2000-07-26 / 1998-04-15

Vapplication CN1998000806122

Number:

@IPC Code: Advanced: G03F 1/00; H01J 37/305; H01L 21/027; H01L 21/3213;

H01L 21/768;

Core: H01L 21/70; more...

IPC-7: H01J 37/305; H01L 21/306; H01L 21/3213; H01L 21/465;

FECLA Code: G03F1/00Z; H01J37/305B2; H01L21/027; H01L21/3213B; H01L21/768C8L;

Priority Number: 1997-04-16 <u>US1997000834356</u>

Legal Status:

PFamily:

PDF	Publication	Pub. Date	Filed	Title	
*	WO9847172A1	1998-10-22	1998-04-15	PATTERN FILM REPAIR USING A GAS ASSISTED FOCUSED PARTICLE BEAM SYSTEM	
*	<u>US6042738</u>	2000-03-28	1997-04-16	Pattern film repair using a focused particle beam system	
Ø	JP2001521678T2	2001-11-06	1998-04-15		
2	EP1641034A2	2006-03-29	1998-04-15	Pattern film repair using a gas assisted focused particle beam system	
&	EP0976152B1	2007-08-08	1998-04-15	PATTERN FILM REPAIR USING A GAS ASSISTED FOCUSED PARTICLE BEAM SYSTEM	
*	EP0976152A1	2000-02-02	1998-04-15	PATTERN FILM REPAIR USING A GAS ASSISTED FOCUSED PARTICLE BEAM SYSTEM	
Ø	DE69838211T2	2008-06-19	1998-04-15	REPARATUR VON MIKROSTRUCKTUREN DURCH GASUNTERSTÜTZTES ÄTZEN MIT FOKUSSIERTEN IONENSTRAHLEN	
	DE69838211C0	2007-09-20	1998-04-15	REPARATUR VON MIKROSTRUCKTUREN DURCH GASUNTERSTÜTZTES ÄTZEN MIT FOKUSSIERTEN IONENSTRAHLEN	
Ø	CN1261458T	2000-07-26	1998-04-15	Pattern film repair using a gas assisted focused	

			particle beam system
CN1261458A	2000-07-26	1998-04-15	Pattern film repair using a gas assisted focused particle beam system
CN1199246C	2005-04-27	1998-04-15	Pattern film repair using a gas assisted focused particle beam system
CA2286638AA	1998-10-22		PATTERN FILM REPAIR USING A GAS ASSISTED FOCUSED PARTICLE BEAM SYSTEM
AU6975098A1	1998-11-11	1998-04-15	Pattern film repair using a gas assisted focused particle beam system
AT0369622E	2007-08-15	1998-04-15	REPARATUR VON MIKROSTRUCKTUREN DURCH GASUNTERSTÜTZTES ÄTZEN MIT FOKUSSIERTEN IONENSTRAHLEN
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PForward References:

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PDF	Patent	Pub.Date	Inventor	Assignee	Title
23	<u>US7264905</u>	2007-09-04	Nagamura; Yoshikazu	Renesas Technology Corp.	Photomask, and method and apparatus for producing the same

None







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